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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR $\mu$ PA2210T1M

## P-CHANNEL MOS FET FOR SWITCHING

#### **DESCRIPTION**

The  $\mu$ PA2210T1M is P-channel MOS Field Effect Transistor designed for power management applications of portable equipments, such as load switch.

#### **FEATURES**

• Low on-state resistance

 $R_{DS(on)1} = 29 \text{ m}\Omega \text{ MAX.} (V_{GS} = -4.5 \text{ V}, I_D = -7.2 \text{ A})$ 

 $R_{DS(on)2}$  = 41 m $\Omega$  MAX. (Vgs = -2.5 V, ID = -3.6 A)

 $R_{DS(on)3} = 81 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = -1.8 \text{ V, Ip} = -3.6 \text{ A)}$ 

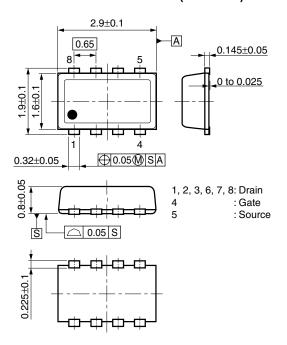
- Built-in gate protection diode
- −1.8 V Gate drive available

#### **ORDERING INFORMATION**

PART NUMBER	PACKING	PACKAGE
$\mu$ PA2210T1M-T1-AT Note	8 mm embossed taping	8-pin VSOF (1629)
μPA2210T1M-T2-AT Note	3000 p/reel	0.011 g TYP.

Note Pb-free (This product does not contain Pb in external electrode and other parts.)

## PACKAGE DRAWING (Unit: mm)



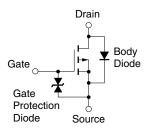
## ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

Drain to Source Voltage (Vgs = 0 V)	VDSS	-20	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	Vgss	∓8	V
Drain Current (DC)	$I_{D(DC)}$	<del>∓</del> 7.2	Α
Drain Current (pulse) Note1	$I_{D(pulse)}$	∓28.8	Α
Total Power Dissipation Note2	P <sub>T1</sub>	1.1	W
Total Power Dissipation (PW = 5 sec) Note2	P <sub>T2</sub>	2.5	W
Channel Temperature	Tch	150	°С
Storage Temperature	Tstg	-55 to +150	°C

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

2. Mounted on glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mmt

## **EQUIVALENT CIRCUIT**



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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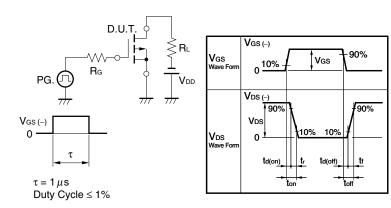
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**ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)** 

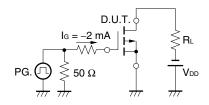
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = -20 V, V <sub>GS</sub> = 0 V			-1	μΑ
Gate Leakage Current	Igss	V <sub>GS</sub> = ∓8 V, V <sub>DS</sub> = 0 V			∓10	μA
Gate to Source Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1 mA	-0.45		-1.5	V
Forward Transfer Admittance Note	y <sub>fs</sub>	$V_{DS} = -10 \text{ V}, I_{D} = -3.6 \text{ A}$	5			s
Drain to Source On-state Resistance Note	R <sub>DS(on)1</sub>	V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -7.2 A		24	29	mΩ
	RDS(on)2	$V_{GS} = -2.5 \text{ V}, I_D = -3.6 \text{ A}$		28	41	mΩ
	R <sub>DS(on)3</sub>	$V_{GS} = -1.8 \text{ V}, I_D = -3.6 \text{ A}$		37	81	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = -10 V,		1350		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V,		235		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		200		pF
Turn-on Delay Time	t <sub>d(on)</sub>	$V_{DD} = -10 \text{ V}, \text{ ID} = -3.6 \text{ A},$		10.7		ns
Rise Time	<b>t</b> r	V <sub>GS</sub> = -4.0 V,		17.1		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		106		ns
Fall Time	<b>t</b> f			71		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = -16 V,		16.3		nC
Gate to Source Charge	Qgs	V <sub>GS</sub> = -4.5 V,		2.7		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = -7.2 A		5.3		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	I <sub>F</sub> = -7.2 A, V <sub>GS</sub> = 0 V		0.87	1.2	V
Reverse Recovery Time	trr	IF = -7.2 A, VGS = 0 V,		46		ns
Reverse Recovery Charge	Qrr	$di/dt = -45 \text{ A}/\mu\text{s}$		15		nC

Note Pulsed

## TEST CIRCUIT 1 SWITCHING TIME

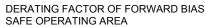


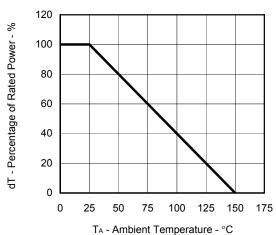
## **TEST CIRCUIT 2 GATE CHARGE**



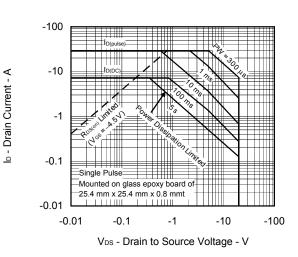
 $\mu$ PA2210T1M

## TYPICAL CHARACTERISTICS (TA = 25°C)

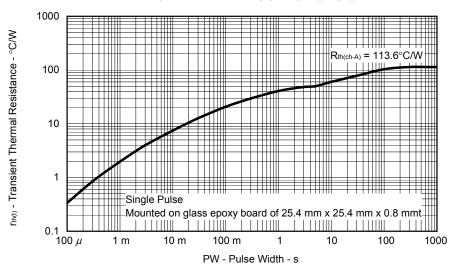




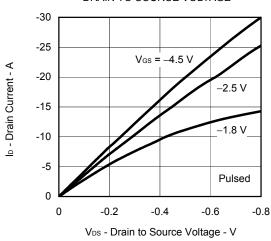
#### FORWARD BIAS SAFE OPERATING AREA



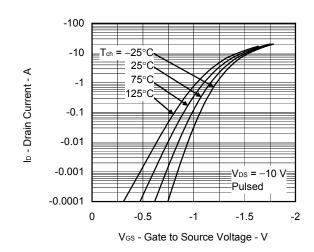
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

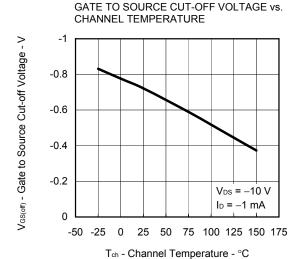


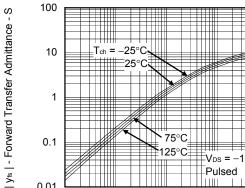
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



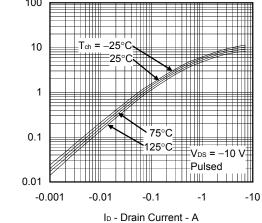
#### FORWARD TRANSFER CHARACTERISTICS





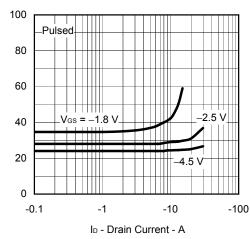


DRAIN CURRENT

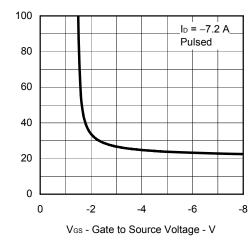


FORWARD TRANSFER ADMITTANCE vs.

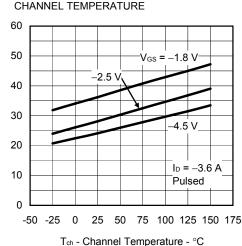




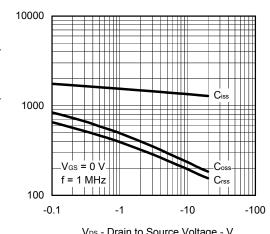
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



V<sub>DS</sub> - Drain to Source Voltage - V

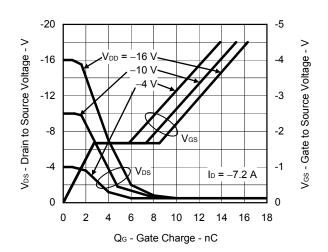
R<sub>DS(cn)</sub> - Drain to Source On-state Resistance - mΩ

R<sub>DS(m)</sub> - Drain to Source On-state Resistance - mΩ

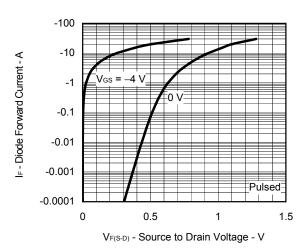
R<sub>DS(m)</sub> - Drain to Source On-state Resistance - mΩ

NEC  $\mu$ PA2210T1M

## DYNAMIC INPUT/OUTPUT CHARACTERISTICS



## SOURCE TO DRAIN DIODE FORWARD VOLTAGE



NEC  $\mu$ PA2210T1M

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